NSN 5962-01-506-3280

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-506-3280

Maximum Power Dissipation Rating:
1.5 watts
Operating Tempurature Range:
-40.0/+85.0 degrees celsius
End Application:
Used in 114e6472g1
Features Provided:
Electrically alterable and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Leaded chip carrier
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
22 input
Terminal Surface Treatment:
Solder
Product Name:
Micrcocicuit, memory, digital, cmos, ee programmable array logic, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts total supply and 7.0 volts total supply
Time Rating Per Chacteristic:
15.00 nanoseconds af output megawatts
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Special Features:
Use program 356a1289p3.Jed to program 356a1409p16 or atf22v10bq-15jc
Terminal Type And Quantity:
28 j-hook
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A458a0